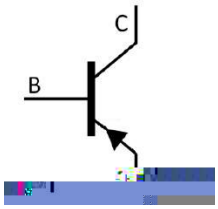
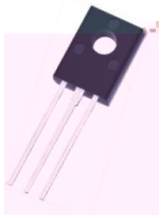
WR0459I ṂṂĿ SQS ÆṀч s Ⅱㄱ Silicon PNP transistor in a TO-126F Plastic Package.

лъ EG46: Йˊ
Complement to BD137.

₹ ᴀ ı ' Ɔ ب ȝ Ầ Ң Ɔ ب
Medium power linear and switching applications.

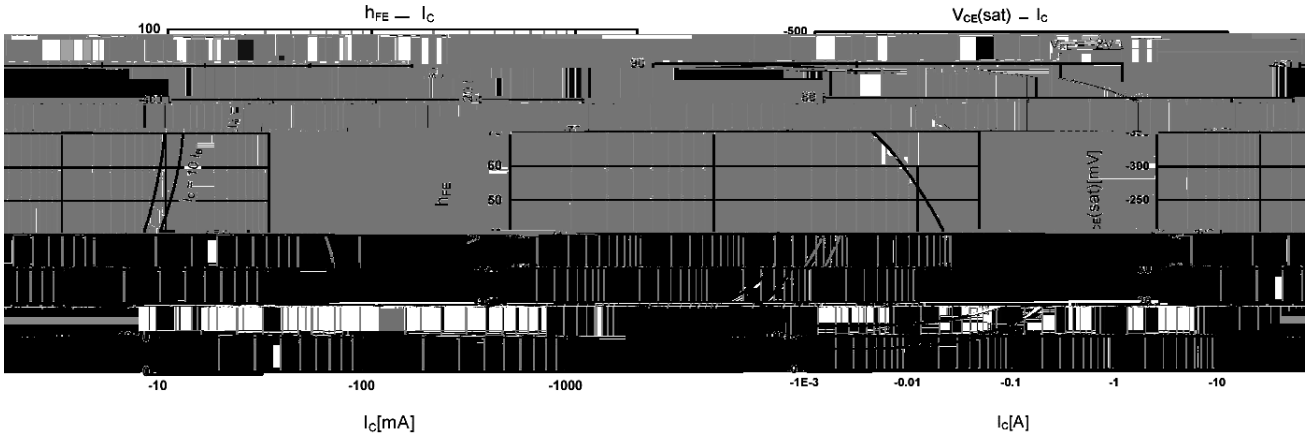


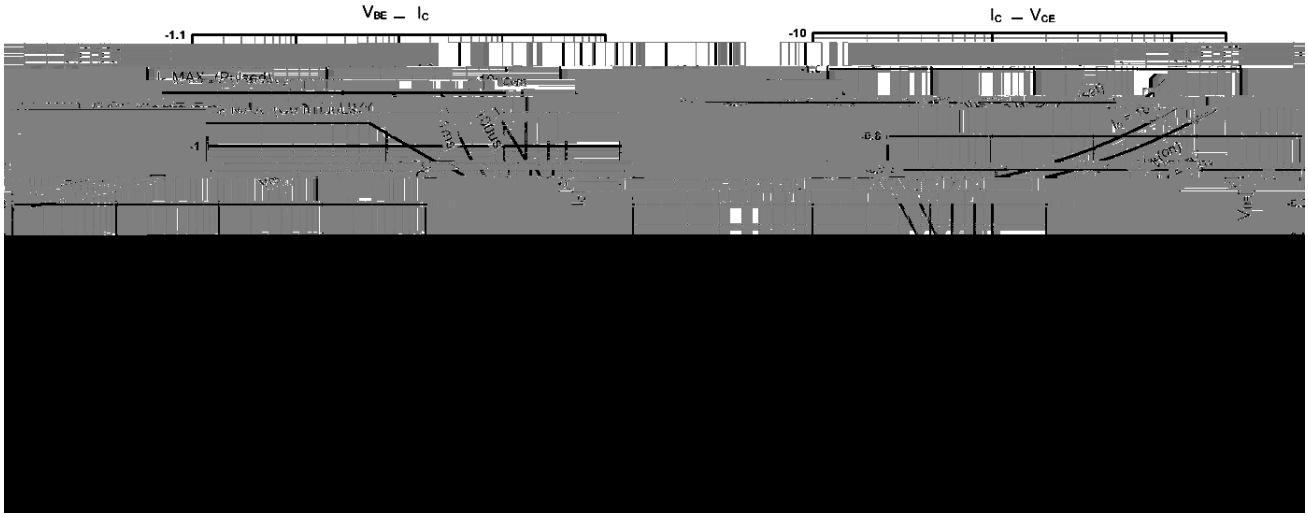


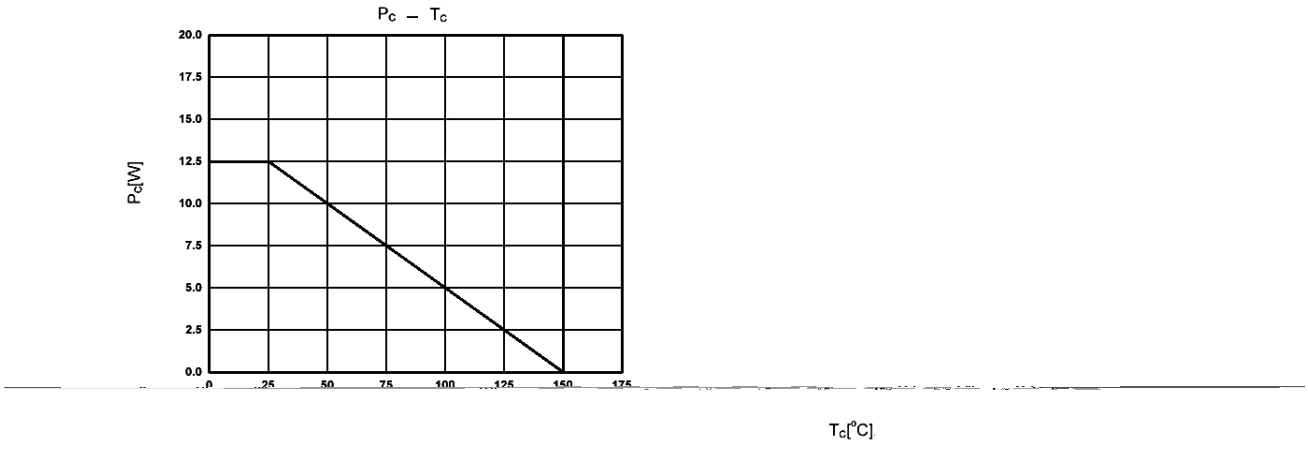
PIN1 χ Emitter PIN 2 χ Collector PIN 3 χ Base

v ˝Ω Parameter	ϒ N Symbol	˝Ω Ö Rating	D Ђ Unit
Collector to Base Voltage	V_{CBO}	-60	V

/ Electrical Characteristic Curve

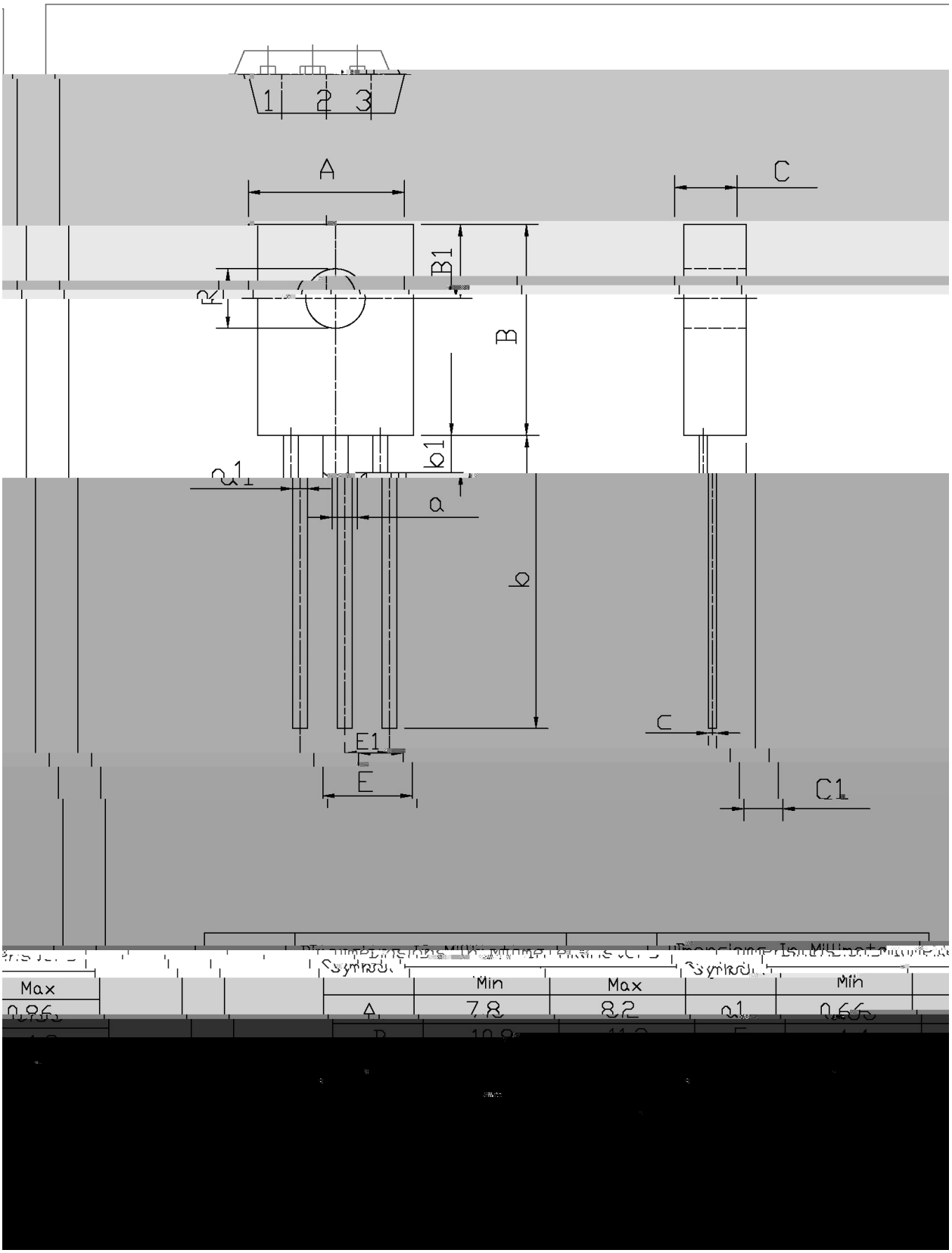






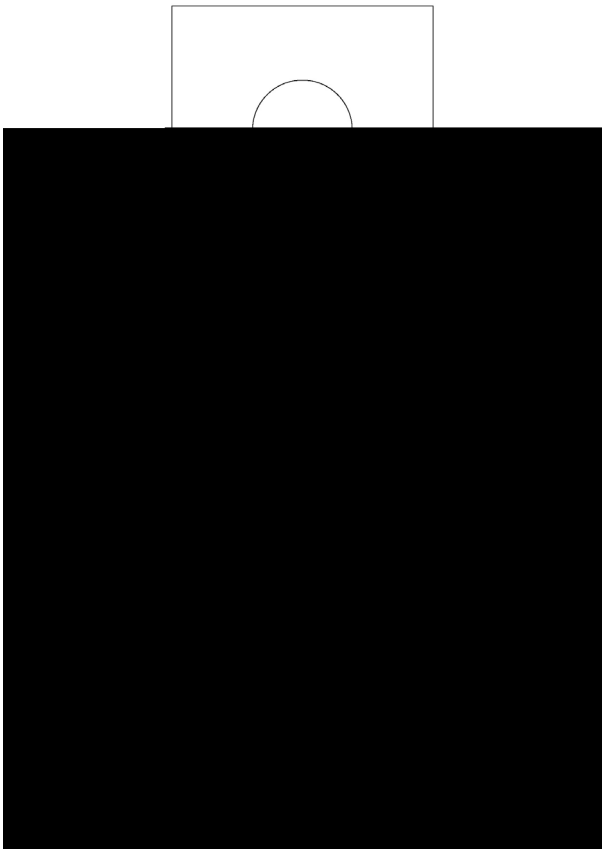
/ Package Dimensions

TO-126T 单位：mm



Symbol	Min	Max	Symbol	Min
		0.86		
A	7.8	8.2	a1	0.66
B	10.8	11.2	E	1.1

/ Marking Instructions



ِ ˝ χ	
EU χ	ѭ ϛ и Ґ
EG46 ; χ	ѭ ғ β ʒ ᴺ
49ⵑ	ѭ k ıн ‘ ⁶ Ґ
---- χ	ѭ ı ғ ӈ ᴺ Ґ ı ₺ ı ғ ӈ ᴺ Ψ ק
Note:	
BR:	Company Code
BD138:	Product Type.
16:	h_{FE} Classifications Symbol
****:	Lot No. Code, code change with Lot No.

( ) / Temperature Profile for Dip Soldering(Pb-Free)

ب ˝ χ

1 Ĺ ♬ □ ỷ 25 Ḱ 150 ɬ ı `H ڑ 60 Ḱ 90sec;

2 Š Ө □ ỷ 255 ° 5 ɬ ı `H ڑ 'Y ﾊ ㎞ 5 ° 0.5sec;

3 ì ˙ ｲ ˛ ɔ ﻩ ỷ ㎞ 2 Ḱ 10 ɬ /sec.

Note:

1.Preheating:25~150 ɬ , Time:60~90sec.

2.Peak Temp.:255 ° 5 ɬ , Duration:5 ° 0.5sec.

3. Cooling Speed: 2~10 ɬ /sec.

/ Resistance to Soldering Heat Test Conditions

□ ỷ χ 270 ° 5 ɬ `H ڑ χ 10 ° 1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

'Ọ ţ ｙ Ł / BULK

Package Type	Units				Dimension	(unit mm^3)
	Units/Tube /	Tubes/Inner Box /	Units/Inner Box /	Inner Boxes/Ou…		